THEORY AND OPTIMIZATION OF GRAPHENE PHOTOTHERMOELECTRIC DETECTORS

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Graphene photothermoelectric detectors

■ Broadband: THz → UV

• Fast: >67 GHz

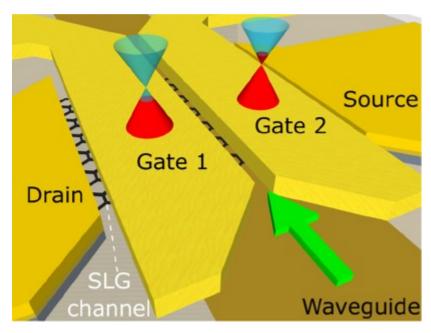
Mišeikis et al., ACS Nano 14, 11190 (2020)

Low power: zero bias





Photothermoelectric effect

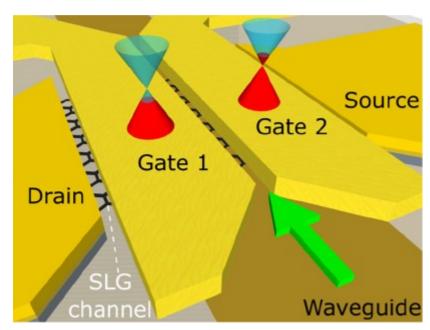


Muench et al., Nano Lett. 19, 7632 (2019)

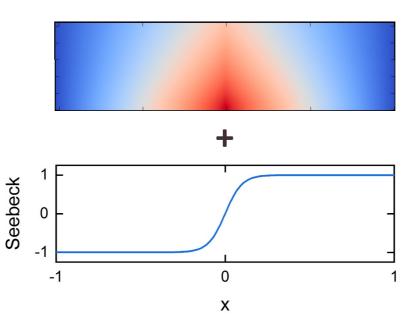




Photothermoelectric effect

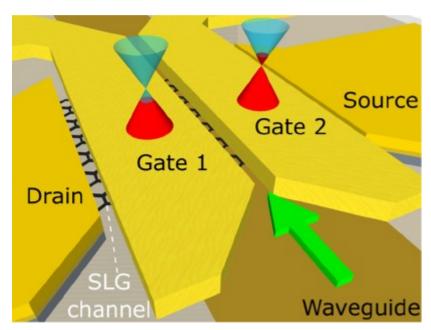


Muench et al., Nano Lett. 19, 7632 (2019)

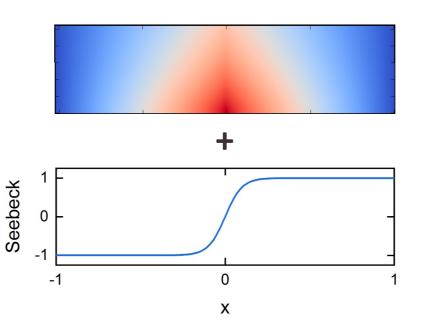




Photothermoelectric effect



Muench et al., Nano Lett. 19, 7632 (2019)



$$V_{\text{PTE}} = \int S(x) \frac{dT_{el}}{dx} dx$$





Approach

Solve the heat equation

$$\nabla^2 T_{el} - \frac{T_{el}}{L_{\rm c}^2} + \frac{P}{\kappa} = 0$$





Approach

Solve the heat equation

$$\nabla^2 T_{el} - \frac{T_{el}}{L_c^2} + \frac{P}{\kappa} = 0$$

Derive figures of merit

$$V_{\text{PTE}} = \int S(x) \frac{dT_{el}}{dx} dx$$

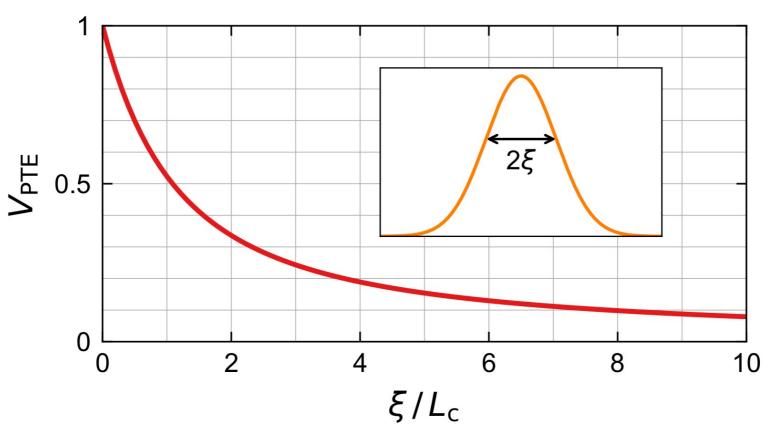
$$I_{\rm PTE} = V_{\rm PTE}/R$$

$$NEP = \sqrt{4kTR}/V_{PTE}/P_{in}$$





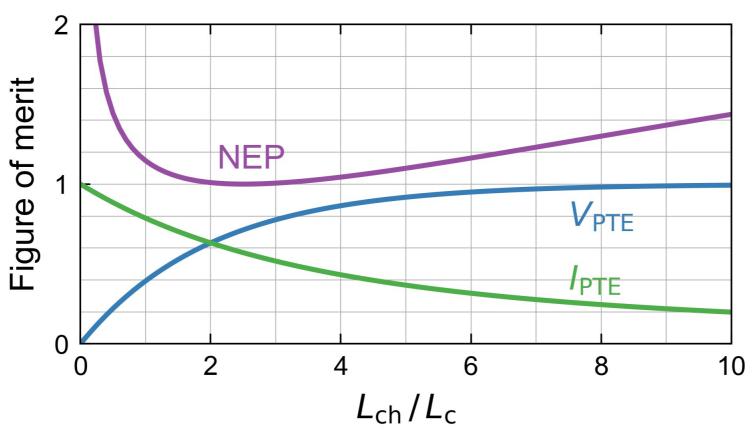
Spot size







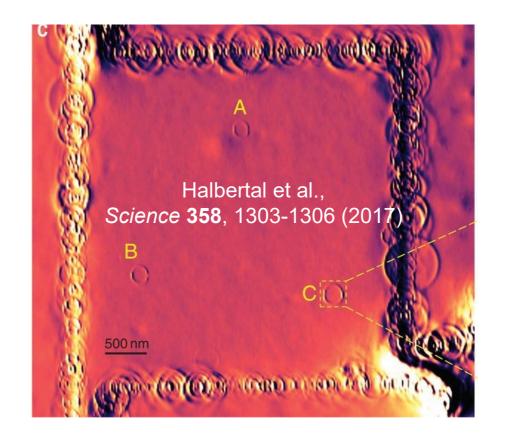
Channel length







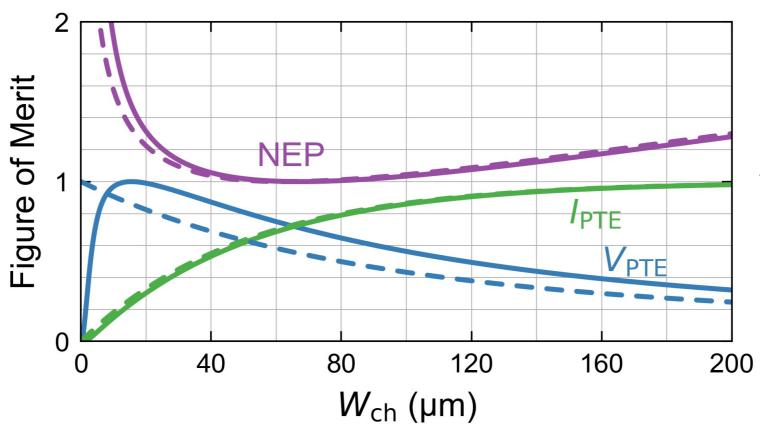
Channel width







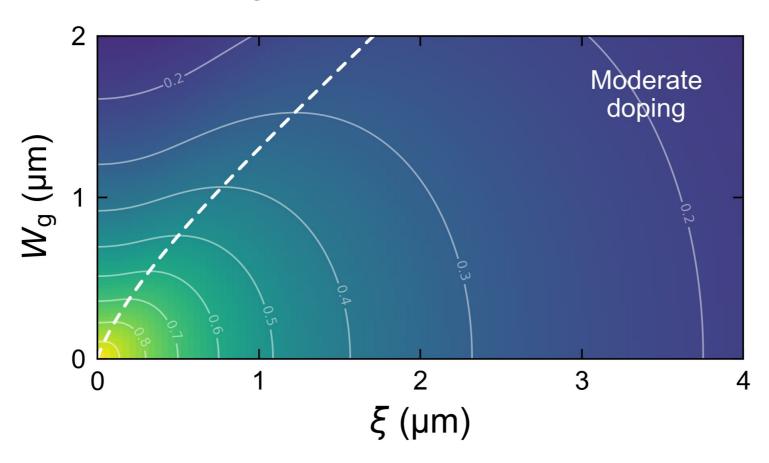
Channel width







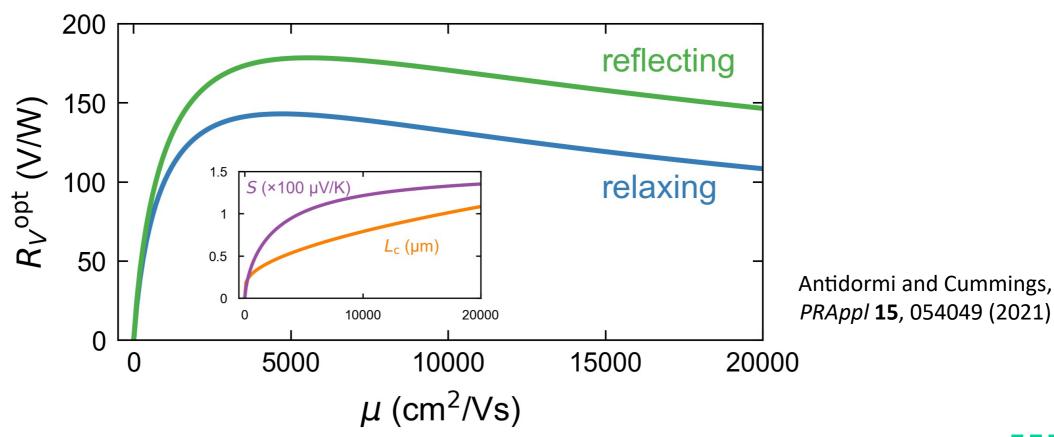
Split gate separation / spot size





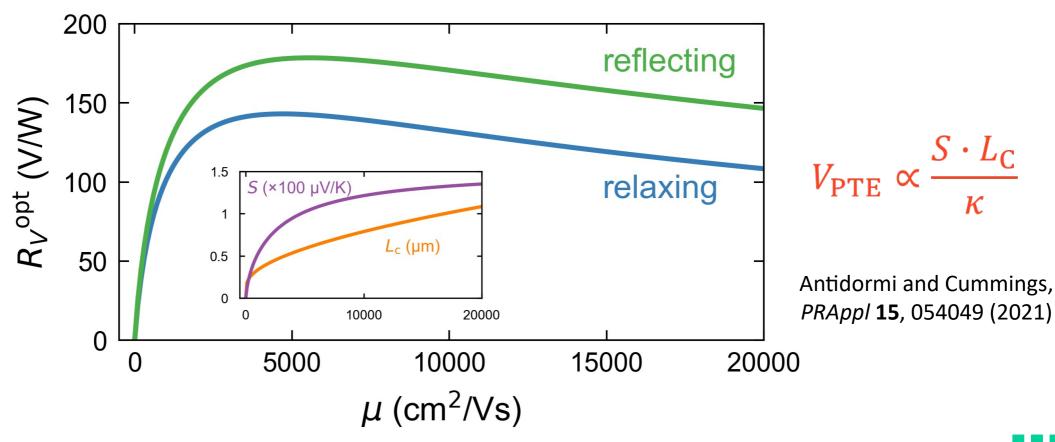


■ Graphene quality → photovoltage



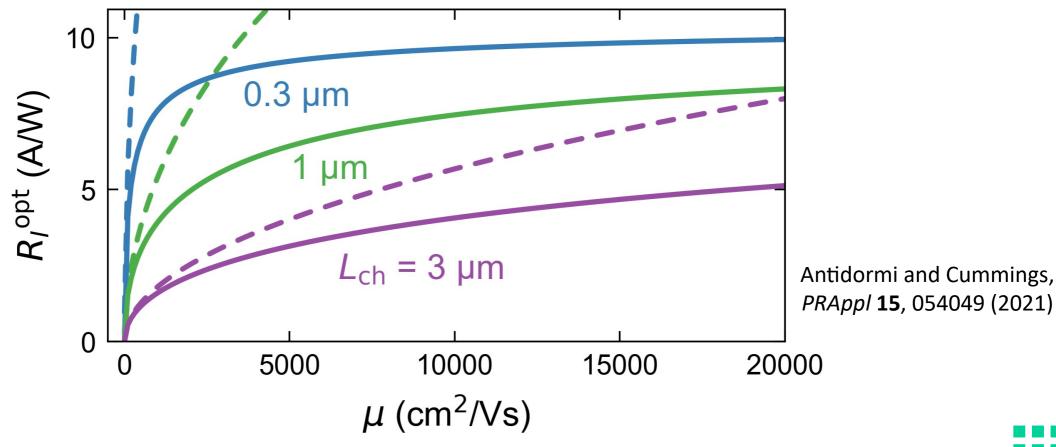


■ Graphene quality → photovoltage



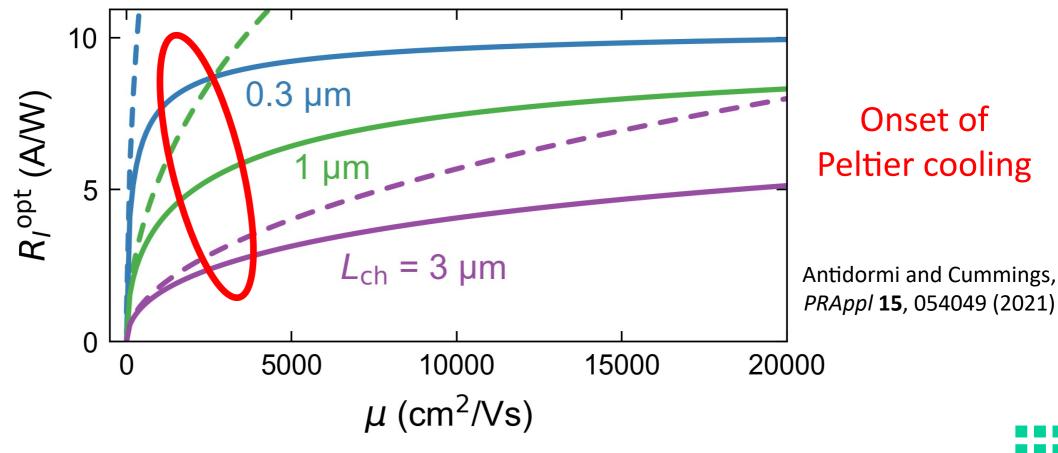


■ Graphene quality → photocurrent





■ Graphene quality → photocurrent





Thank you for your attention!



agreement No 825272 (ULISSES).